# **ON Semiconductor**

# Is Now



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# Internally Compensated Dual Low Noise Operational Amplifier

The 5532 is a dual high-performance low noise operational amplifier. Compared to most of the standard operational amplifiers, such as the 1458, it shows better noise performance, improved output drive capability and considerably higher small-signal and power bandwidths.

This makes the device especially suitable for application in high-quality and professional audio equipment, instrumentation and control circuits, and telephone channel amplifiers. The op amp is internally compensated for gains equal to one. If very low noise is of prime importance, it is recommended that the 5532A version be used because it has guaranteed noise voltage specifications.

#### **Features**

• Small-Signal Bandwidth: 10 MHz

• Output Drive Capability: 600 Ω, 10 V<sub>RMS</sub>

Input Noise Voltage: 5.0 nV/√Hz (Typical)

• DC Voltage Gain: 50000

• AC Voltage Gain: 2200 at 10 kHz

• Power Bandwidth: 140 kHz

• Slew Rate: 9.0 V/us

• Large Supply Voltage Range:  $\pm 3.0$  to  $\pm 20$  V

• Compensated for Unity Gain

• Pb-Free Packages are Available



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SOIC-8 D SUFFIX CASE 751



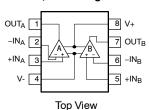
PDIP-8 N SUFFIX CASE 626



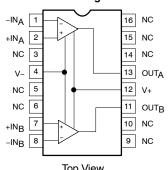
SOIC-16 WB D SUFFIX CASE 751G

### PIN CONNECTIONS

#### N, D8 Packages



### D Package\*



\*SOL and non-standard pinout.

### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 6 of this data sheet.

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

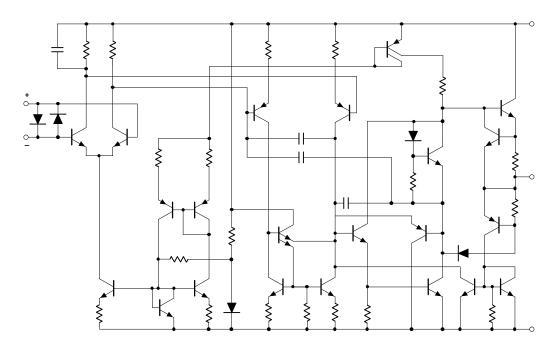


Figure 1. Equivalent Schematic (Each Amplifier)

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Supply Voltage	V <sub>S</sub>	±22	V
Input Voltage	V <sub>IN</sub>	±V <sub>SUPPLY</sub>	V
Differential Input Voltage (Note 1)	V <sub>DIFF</sub>	±0.5	V
Operating Temperature Range NE5532/A SA5532 SE5532/A	T <sub>amb</sub>	0 to 70 -40 to +85 -55 to +125	°C
Storage Temperature	T <sub>stg</sub>	−65 to +150	°C
Junction Temperature	T <sub>j</sub>	150	°C
Maximum Power Dissipation, T <sub>amb</sub> = 25°C (Still-Air)  8  D8 Package  8  N Package  16  D Packagee	P <sub>D</sub>	780 1200 1200	mW
Thermal Resistance, Junction-to-Ambient 8 D8 Package 8 N Package 16 D Packagee	$R_{ heta JA}$	182 130 140	°C/W
Lead Soldering Temperature (10 sec max)	T <sub>sld</sub>	230	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Diodes protect the inputs against overvoltage. Therefore, unless current-limiting resistors are used, large currents will flow if the differential input

voltage exceeds 0.6 V. Maximum current should be limited to  $\pm$  10 mA.

DC ELECTRICAL CHARACTERISTICS ( $T_{amb}$  = 25°C;  $V_S$  =  $\pm$  15 V, unless otherwise noted.) (Notes 2, 3 and 4)

			SE5532/A		NE55	532/A, SA	5532		
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Min	Тур	Max	Unit
Offset Voltage	V <sub>OS</sub>	-	-	0.5	2.0	-	0.5	4.0	mV
	-	Overtemperature	-	-	3.0	-	_	5.0	mV
	$\Delta V_{OS}/\Delta T$	-	-	5.0	-	-	5.0	-	μV/°C
Offset Current	los	-	-	-	100	-	10	150	nA
	-	Overtemperature	-	-	200	-	_	200	nA
	$\Delta I_{OS}/\Delta T$	-	-	200	-	-	200	-	pA/°C
Input Current	Ι <sub>Β</sub>	-	-	300	500	-	300	800	nA
	-	Overtemperature	-	_	700	-	_	1000	nA
	$\Delta I_{B}/\Delta T$	-	-	5.0	-	-	5.0	-	nA/°C
Supply Current	I <sub>CC</sub>	-	-	8.0	10.5	-	8.0	16	mA
	-	Overtemperature	-	-	13	-	_	-	
Common-Mode Input Range	$V_{CM}$	-	±12	±13	-	±12	±13	-	V
Common-Mode Rejection Ratio	CMRR	-	80	100	-	70	100	-	dB
Power Supply Rejection Ratio	PSRR	-	-	10	50	-	10	100	μV/V
Large-Signal Voltage Gain	A <sub>VOL</sub>	$R_L \ge 2.0 \text{ k}\Omega; V_O = \pm 10 \text{ V}$	50	100	-	25	100	=	V/mV
		Overtemperature	25	-	-	15	_	-	
		$R_L \ge 600 \Omega; V_O = \pm 10 V$	40	50	-	15	50	-	
		Overtemperature	20	-	-	10	_	-	
Output Swing	V <sub>OUT</sub>	$R_L \ge 600 \Omega$	±12	±13	-	±12	±13	_	V
		Overtemperature	±10	±12	-	±10	±12	-	
		$R_L \ge 600 \Omega; V_S = \pm 18 V$	±15	±16	-	±15	±16	-	
		Overtemperature	±12	±14	-	±12	±14	-	
		$R_L \ge 2.0 \text{ k}\Omega$	±13	±13.5	-	±13	±13.5	-	
		Overtemperature	±12	±12.5	-	±10	±12.5	-	
Input Resistance	R <sub>IN</sub>	-	30	300	-	30	300	-	kΩ
Output Short Circuit Current	I <sub>SC</sub>	-	10	38	60	10	38	60	mA

<sup>2.</sup> Diodes protect the inputs against overvoltage. Therefore, unless current-limiting resistors are used, large currents will flow if the differential input voltage exceeds 0.6 V. Maximum current should be limited to  $\pm 10$  mA.

For operation at elevated temperature, derate packages based on the package thermal resistance.
 Output may be shorted to ground at V<sub>S</sub> = ± 15 V, T<sub>amb</sub> = 25°C. Temperature and/or supply voltages must be limited to ensure dissipation rating is not exceeded.

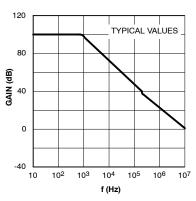
# AC ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25^{\circ}C$ ; $V_{S} = \pm 15$ V, unless otherwise noted.)

			NE/SE5532/A, SA5532			
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
Output Resistance	R <sub>OUT</sub>	$A_V$ = 30 dB Closed-loop f = 10 kHz, $R_L$ = 600 $\Omega$	-	0.3	-	Ω
Overshoot	-	Voltage-Follower				%
		$V_{IN}$ = 100 m $V_{P-P}$	-	10	-	
		$C_L = 100 \text{ pF}; R_L = 600 \Omega$				
Gain	A <sub>V</sub>	f = 10 kHz	-	2.2	-	V/mV
Gain Bandwidth Product	GBW	$C_L = 100 \text{ pF}; R_L = 600 \Omega$	-	10	=	MHz
Slew Rate	SR	-	-	9.0	-	V/μs
Power Bandwidth	=	V <sub>OUT</sub> = ±10 V	-	140	=	kHz
		$V_{OUT}$ = ±14 V; $R_L$ = 600 $\Omega$	-	100	-	
		$V_{CC} = \pm 18 V$				

# **ELECTRICAL CHARACTERISTICS** ( $T_{amb}$ = 25°C; $V_{S}$ = $\pm$ 15 V, unless otherwise noted.)

			NE/SE5532		NE/SA/SE5532A				
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Min	Тур	Max	Unit
Input Noise Voltage	V <sub>NOISE</sub>	f <sub>O</sub> = 30 Hz	-	8.0	-	-	8.0	12	nV/√Hz
		f <sub>O</sub> = 1.0 kHz	-	5.0	-	-	5.0	6.0	
Input Noise Current	I <sub>NOISE</sub>	f <sub>O</sub> = 30 Hz	-	2.7	-	-	2.7	-	pA/√ <del>Hz</del>
		f <sub>O</sub> = 1.0 kHz	-	0.7	-	-	0.7	_	
Channel Separation	-	$f$ = 1.0 kHz; $R_S$ = 5.0 kΩ	_	110	-	-	110	_	dB

### TYPICAL PERFORMANCE CHARACTERISTICS



60 TYPICAL VALUES RF =  $10 \text{ k}\Omega$ ; RE =  $100 \Omega$ 40 **GAIN (dB)** RF =  $9 \text{ k}\Omega$ ; RE =  $1 \text{ k}\Omega$  $RF = 1 k\Omega; RE =$ 0 -20 10<sup>3</sup> 10<sup>4</sup> 10<sup>5</sup> 10<sup>6</sup> 10<sup>7</sup> 10<sup>8</sup> f (Hz)

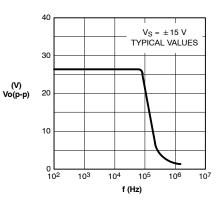
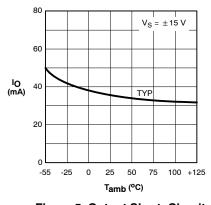
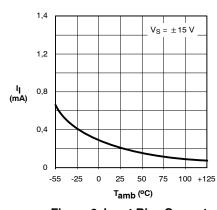


Figure 2. Open-Loop Frequency Response

Figure 3. Closed-Loop Frequency Response

Figure 4. Large-Signal Frequency Response





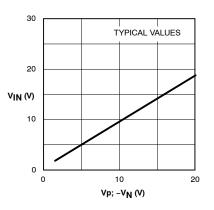
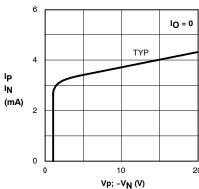
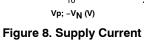


Figure 5. Output Short-Circuit Current

Figure 6. Input Bias Current

Figure 7. Input Common-Mode Voltage Range





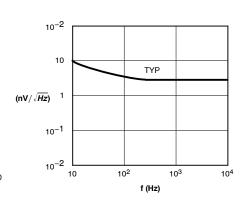
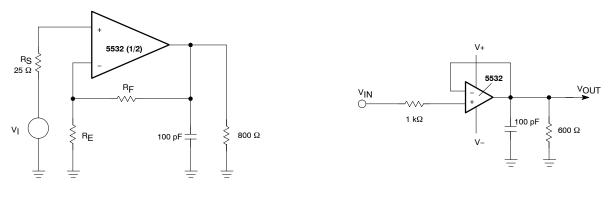


Figure 9. Input Noise Voltage Density



**Closed-Loop Frequency Response** 

Voltage-Follower

Figure 10. Test Circuits

#### **MARKING DIAGRAMS** 8 <u>A A A A</u> 8 A A A A 8 A A A A NE5532AN NE5532N SA5532N SE5532N N5532 N5532 S5532 **AWL AWL** AWL **AWL ALYWA** ALYW ALYWA YYWWG YYWWG YYWWG YYWWG 888 1 8 8 8 8 1 1 1 1 SOIC-8 PDIP-8 **D SUFFIX N SUFFIX CASE 751 CASE 626** NE5532D AWLYYWWG 1 1 1 1 1 1 1 1 1 1 1 SOIC-16 WB **D SUFFIX CASE 751G** = Assembly Location WL, L = Wafer Lot

= Year WW, W = Work Week G or ■ = Pb-Free Packagee

YY, Y

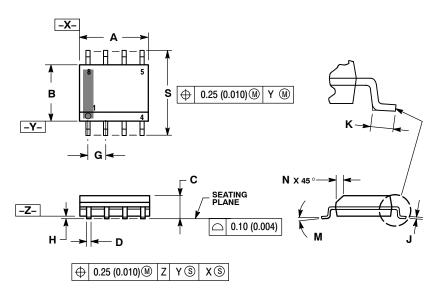
### **ORDERING INFORMATION**

Device	Description	Temperature Range	Shipping <sup>†</sup>
NE5532AD8	8-Pin Plastic Small Outline (SO-8) Package		98 Units / Rail
NE5532AD8G	8-Pin Plastic Small Outline (SO-8) Package (Pb-Free)	_	98 Units / Rail
NE5532AD8R2	8-Pin Plastic Small Outline (SO-8) Package		2500 / Tape & Reel
NE5532AD8R2G	8-Pin Plastic Small Outline (SO-8) Package (Pb-Free)	-	2500 / Tape & Reel
NE5532AN	8-Pin Plastic Dual In-Line Package (PDIP-8)		50 Units / Rail
NE5532ANG	8-Pin Plastic Dual In-Line Package (PDIP-8) (Pb-Free)	-	50 Units / Rail
NE5532D	16-Pin Plastic Small Outline (SO-16 WB) Package		47 Units / Rail
NE5532DG	16-Pin Plastic Small Outline (SO-16 WB) Package (Pb-Free)		47 Units / Rail
NE5532DR2	16-Pin Plastic Small Outline (SO-16 WB) Package	- 0 to 70°C	1000 Tape & Reel
NE5532DR2G	16-Pin Plastic Small Outline (SO-16 WB) Package (Pb-Free)		1000 Tape & Reel
NE5532D8	8-Pin Plastic Small Outline (SO-8) Package		98 Units / Rail
NE5532D8G	8-Pin Plastic Small Outline (SO-8) Package (Pb-Free)	-	98 Units / Rail
NE5532D8R2	8-Pin Plastic Small Outline (SO-8) Package		2500 / Tape & Reel
NE5532D8R2G	8-Pin Plastic Small Outline (SO-8) Package (Pb-Free)	-	2500 / Tape & Reel
NE5532N	8-Pin Plastic Dual In-Line Package (PDIP-8)		50 Units / Rail
NE5532NG	8-Pin Plastic Dual In-Line Package (PDIP-8) (Pb-Free)	-	50 Units / Rail
SA5532N	8-Pin Plastic Dual In-Line Package (PDIP-8)		50 Units / Rail
SA5532NG	8-Pin Plastic Dual In-Line Package (PDIP-8) (Pb-Free)	−40 to +85°C	50 Units / Rail
SE5532AD8	8-Pin Plastic Small Outline (SO-8) Package		98 Units / Rail
SE5532AD8G	8-Pin Plastic Small Outline (SO-8) Package (Pb-Free)	_	98 Units / Rail
SE5532AD8R2	8-Pin Plastic Small Outline (SO-8) Package	1	2500 / Tape & Reel
SE5532AD8R2G	8-Pin Plastic Small Outline (SO-8) Package (Pb-Free)	–55 to +125°C	2500 / Tape & Reel
SE5532N	8-Pin Plastic Dual In-Line Package (PDIP-8)	1	50 Units / Rail
SE5532NG	8-Pin Plastic Dual In-Line Package (PDIP-8) (Pb-Free)		50 Units / Rail

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **PACKAGE DIMENSIONS**

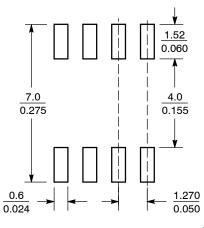
### SOIC-8 NB CASE 751-07 **ISSUE AK**



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) DER SIDE PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
O	1.35	1.75	0.053	0.069
ם	0.33	0.51	0.013	0.020
G	1.27	1.27 BSC		0 BSC
Н	0.10	0.25	0.004	0.010
7	0.19	0.25	0.007	0.010
Κ	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

### **SOLDERING FOOTPRINT\***



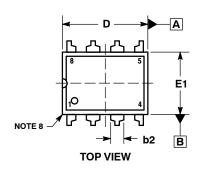
 $\left(\frac{\text{mm}}{\text{inches}}\right)$ SCALE 6:1

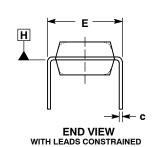
<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

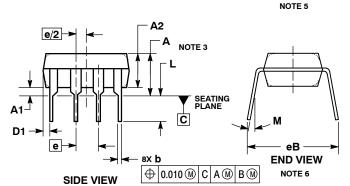
#### PACKAGE DIMENSIONS

### 8-Pin Plastic Dual In-Line Package (PDIP-8) **N SUFFIX**

CASE 626-05 ISSUE N







- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: INCHES.
- 2. CONTROLLING DIMENSION: INCHES.
  3. DIMENSIONS A, A1 AND L ARE MEASURED WITH THE PACK-
- AGE SEATED IN JEDEC SEATING PLANE GAUGE GS-3.

  4. DIMENSIONS D, D1 AND E1 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS, MOLD FLASH OR PROTRUSIONS ARE NOT TO EXCEED 0.10 INCH.
- TO EXCEED 0.10 INCH.

  5. DIMENSION E IS MEASURED AT A POINT 0.015 BELOW DATUM PLANE H WITH THE LEADS CONSTRAINED PERPENDICULAR TO DATUM C.

  6. DIMENSION E IS MEASURED AT THE LEAD TIPS WITH THE LEADS UNCONSTRAINED.

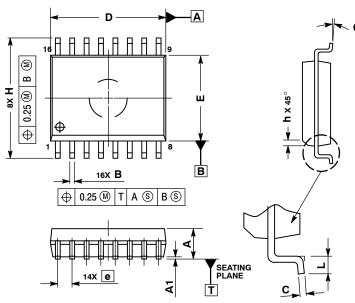
  7. DATUM PLANE H IS COINCIDENT WITH THE BOTTOM OF THE LEADS, WHERE THE LEADS EXIT THE BODY.

- PACKAGE CONTOUR IS OPTIONAL (ROUNDED OR SQUARE CORNERS).

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	-	0.210		5.33
A1	0.015		0.38	
A2	0.115	0.195	2.92	4.95
b	0.014	0.022	0.35	0.56
b2	0.060	TYP	1.52	TYP
С	0.008	0.014	0.20	0.36
D	0.355	0.400	9.02	10.16
D1	0.005		0.13	
E	0.300	0.325	7.62	8.26
E1	0.240	0.280	6.10	7.11
е	0.100 BSC		2.54	BSC
eB		0.430		10.92
L	0.115	0.150	2.92	3.81
М		10°		10°

#### PACKAGE DIMENSIONS

### SOIC-16 WB **D SUFFIX** CASE 751G-03 ISSUE D

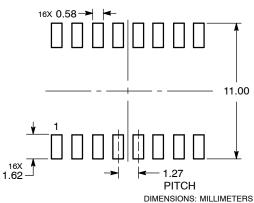


#### NOTES:

- DIMENSIONS ARE IN MILLIMETERS.
   INTERPRET DIMENSIONS AND TOLERANCES. PER ASME Y14.5M, 1994.
- DIMENSIONS D AND E DO NOT INLCUDE
- MOLD PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS				
DIM	MIN	MAX			
Α	2.35	2.65			
A1	0.10	0.25			
В	0.35	0.49			
С	0.23	0.32			
D	10.15	10.45			
Е	7.40	7.60			
е	1.27	BSC			
Н	10.05	10.55			
h	0.25	0.75			
L	0.50	0.90			
а	0 °	7 °			

#### **SOLDERING FOOTPRINT**



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